



[Richar taken from Lionel Levin]

Identity config on square goid.

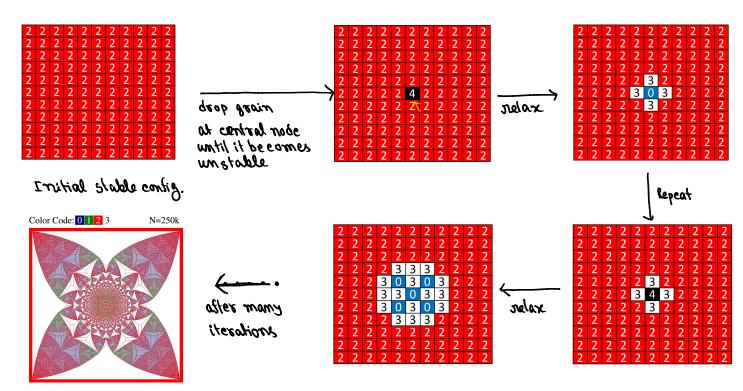
Centrally sed growing sand pile.

Both have similar geometrie structures. For now we study the second class of patterns.

Centrally Sed growing sandpiles

On intimite square gold Z2.

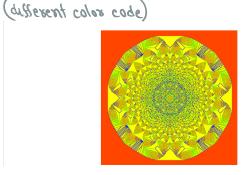
Threshold height &c= 4.



25 × 104 grains added

The pattern depends on the initial consiguration.



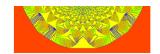


For 20=3, avalanche does not stop.

For $\lambda_0 \rightarrow -\infty$, the boundary of the pattern becomes a Euclidean circle.



Initial config 20=1



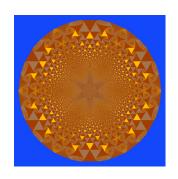
£ 0 = 0

of the pattern becomes a Euclidean civele.

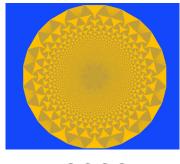
[Anne Fey ??]

The pattern depends on the grid.

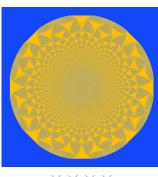
Initial height 20=0







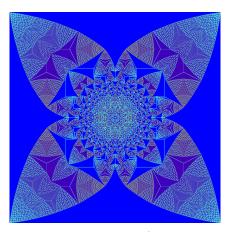




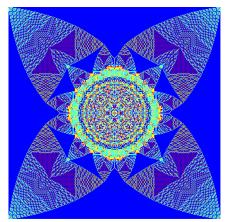


[Patterns taken from Wesley Pegden. For more examples of beautiful patterns see his website]

Higher dimension



Pattern on 22² Initial height 20=2

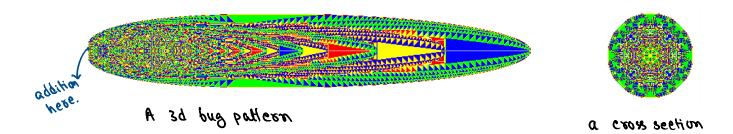


A slice of the poldern on \mathbb{Z}^3 Linux $2_0 = 4$

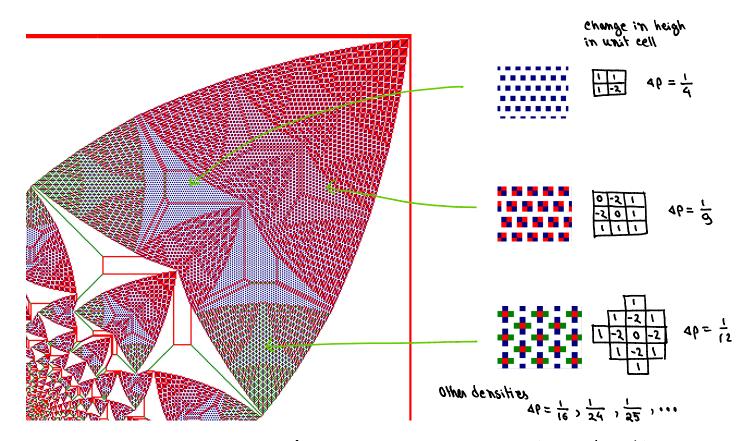
[Pattern taken from Lionel levin]

Asymmetric toppling on Z3

[shar and sadhu, JSM (2013) P1106]



Internal structure: In general patterns are made of patches inside which heights one periodic.



There is a large namge of possible periodic arrangements inside patches. A classification of them can be found in an article [sodjan Ostojic, Physica A 318(2003), 187]

Boundovies of patches are sharp.

Proportionale growth





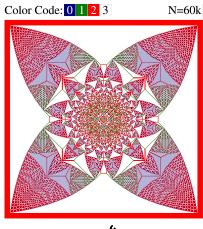


4×105

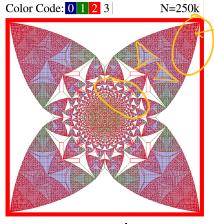
[shar and sadhu, JSM (2013) P1106]

IN eniore bobba to redmun eniososomi

With increasing N, more and more internal structures are formed and once formed all grow Keeping their relative size same such that the overall shape remains same. Patterning and growth happens together.



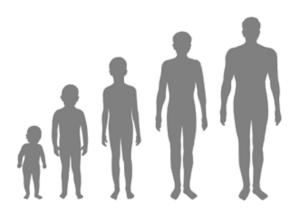
N= 6×104



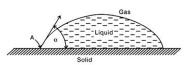
 $N = 25 \times 10^4$ Pattern nescoled to be of same size.

This is called proportionate growth.

A motivation for us.



Animals grow in a highly coordinated babhion. It is a challenging problem in duelopmental biology to understand the bunc mechanism for such growth.



A simple example of proportionate growth in nature, but lacks complex internal structures.

How to construct a model where local dynamics gerwate a complex pattern which grows proportionately without a control regulation and also robust.

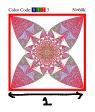
[conventional growth models like disturion limited aggregation models invasion percolation do not have these properties]

Characterization of the pattern

What we want to characterise.



$$(\mathcal{Z},\mathcal{Z}) = \left(\frac{\lambda_{N}}{\lambda_{N}}, \frac{\lambda_{N}}{\lambda_{N}}\right)$$



For larger N, the pattern grows and new internal structure emerge. As a nexult, for the nescaled pattern, size remains some but structur gets more resolved.

We want to characterize the asymptotic rescaled pattern in $N \to \infty$ limit.

Convergence of sandpile pattern.

but $2_{N}(x,y)$ is height at site (x,y) for a pattern generated by adding N growns at the center (0,0) and relaxing the configuration.

L1 = floor function.

Evidently there is no pointwise convergence for $\overline{X}_N(2,2)$ in $N\to\infty$ limit. Instead, there is weak convergence.

The bounded measurable function $\overline{\chi}_{N}(3,2)$ converges weakly as $N\to\infty$ limit, $\overline{\chi}_{N}(3,2)\to P(3,2)$

such that, for any continuous test function $\alpha(3,2)$ with compact support

$$\int dz dz \, \bar{z}_{N}(z,z) \propto (z,z) \longrightarrow \int dz dz \, \rho(z,z) \propto (z,z)$$

Precise theorem from "Convergence of the Abelian sandpile" Wesley Pegden & Charles Smort,

Duke Math J, 162 (2013), 627.

Theorem : [for ASM on Rd with necest raighbor toppling, no sink site, addition at center of initial empty background]

The nescaled sandpiles $\widetilde{Z}_{N}(x):=\widetilde{Z}_{N}\left(N^{N}x\right)$ converge weakly-* to a sunction $P\in L^{\infty}\left(\mathbb{R}^{d}\right)$ as $n\to\infty$. Moreover, the limit P satisfies $\int_{\mathbb{R}^{d}}P\,dx=1$, $0\leq P\leq 2d-1$, and P=0 in $\mathbb{R}^{d}\setminus B_{R}$ for some R>0.

→ space of bounded measurable functions on IR.

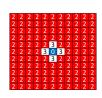
<u>Note comment</u>: An upper bound an diameter of BR in due to [levin, Percs, Pot Anal 30(2009)] which says that for every E > 0 there is a C = C(E,d) > 0 such that

$$\{\widetilde{z}_{N} > o\} \subseteq \mathcal{B}\left((q - \epsilon)/\beta'/\frac{q}{2} | \frac{n_{q}}{2} + G\right)$$

for all N>0. Here 1B,1 := volume of whit ball.



For the example, with initial 2=2 background it can be shown by induction that the boundary is square [Ostojie (2003)].





first note that boundary sites have height 3 and corner ones have height 2.

If an avalanch reaches any boundary site, then all boundary sites topple - shifts the boundary by one unit to the same boundary height consig.

Observing that the pattern is compact,

 $N_{\rm H} = c_1 IN + sub-leading in large N.$

[Fey, levin, Peres (2010), JSP 138, 143]
[Fey, Meester, Redig (2007). Ann Prob, 37, 654]

" stability and percolation in infinite volume sandpiles"

Our work: (with Deepak Dhan)

We determine the p(3,2) in terms of discrete holomorphic function.

Over all idea? on 29.

 $T_{N}(x,y) := number of toppling at site <math>(x,y)$ in the pattern generated by adding N-grains.

[Ostojic, Physica A 318 (2003), 187] [Dhan, Sadhu, Chomdoa, EPL, 85 (2009), 48002]

[toppling function, Odometer function]

Conservation of particle number

$$O_{\mathcal{E}}^{\mathcal{E}} \partial_{\mathcal{E}}^{\mathcal{E}} \partial_{\mathcal{E}}^{\mathcal{$$

Rescaled variables

$$T_{N}(x,y) \simeq \Lambda_{N}^{\beta} \underline{\Phi(\xi, \underline{z})} + \text{subleading in } \Lambda_{N} > 1.$$

$$2_{N}(x,y) \simeq \rho(\xi, \underline{z}) + \text{subleading} > 2.$$

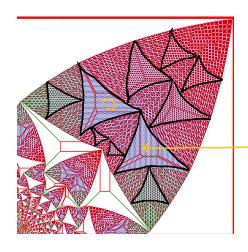
$$V_{B-2}^{N} \left(g^{\frac{2}{3}\frac{2}{3}} + g^{\frac{2}{3}\frac{2}{3}} \right) \phi(z^{2}) = b(z^{2}) - b^{0} - \frac{V_{B}^{N}}{N} g(\overline{z}) g(\overline{z})$$

For ASM on \mathbb{Z}^2 , $\beta=2$ and it gives

$$\Delta_{\vec{\sigma}} \Phi = 6 - 6^{\circ} - y \, g(\underline{y})$$

This is like an electrostatic problem: ϕ is the potential due to areal charge density $\rho-\rho_0$ and a point charge λ at origin. If we know $\phi(\bar{n})$, then we know the asymptotic pattern $\rho(\bar{n})$, which is our goal.

How do we know \$ 2 . For this we use a lew basic geatures in the pattern.



- (1) The asymptotic pattern is union of Patches inside which heights one periodic.
- (2) Asymptotic density inside patches is constant.
- (3) Defect lines contribute sublading order in enal density $p(\bar{x})$.

<u>Proposition</u> ? Inside the periodic patches, $\phi(3,2)$ is atmost a quadratic polynomial.

$$\phi(3,2) = \alpha 3^2 + b 2^2 + e 32 + d3 + e2 + f$$

Angument: Inside a patch, ϕ in Taylor expandable



$$\phi(\S_{0} + \underline{4}\S_{0}, \Sigma_{0} + \underline{4}\Sigma) - \phi(\S_{0}, \Sigma_{0}) \\
= \alpha_{1}4\S_{0} + b_{1}4\Sigma_{0} + \alpha_{2}(4\S_{0})^{2} + b_{2}(4\Sigma_{0})^{2} + h_{2}4\S_{0}\Sigma_{0} \\
+ \alpha_{2}(4\S_{0})^{3} + \cdots$$

$$= \alpha_{1} \alpha_{2}^{2} + b_{1} \alpha_{2}^{2} + \alpha_{2}^{2} (\alpha_{3}^{2})^{2} + \cdots$$

$$+ \alpha_{3}^{2} (\alpha_{3}^{2})^{3} + \cdots$$

This selates to integer toppling sunction

$$T_{\mu}(x,y) = N_{\mu}^{2} \phi(x,y) + subkading in N_{\mu}$$

$$\Rightarrow T_{N}(x_{0}+4x, y_{0}+4y) - T_{N}(x_{0}, y_{0}) = \Lambda_{N} \alpha_{1} \alpha x + \Lambda_{N} b_{1} \alpha y + \alpha_{2} (\alpha x)^{2} + b_{2}(\alpha y)^{2}$$

$$+ b_{2} \alpha x \alpha y + \alpha_{3} \frac{(\alpha x)^{3}}{\Lambda_{N}} + \cdots$$

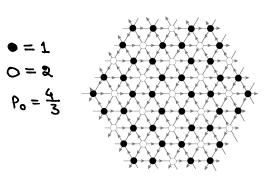
Because $T_N(x,y)$ is an integer valued sunction, the disserence jumps discontinuously at every $4x \sim N_N^{1/3}$ due to the $(4x)^3$ term. This would then mean that there are large number of defect lines at distances $\sim N_N^{1/3}$ in a patch of size $\sim N_N$. This we don't see in the pattern, and therefore any term of degree 3 or higher must be absent in $\phi(3,2)$.

How does it help us determine of?

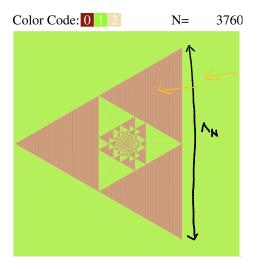
- () Rescaled toppling function in the asymptotic patch is a piece-wise quadratic function.
- () Inside each patch, we need to determine five parameters in $\varphi(3,2)=\alpha 3^2+b 2^2+c 32+d 2+e 2+f$
- first (c) Continuity of ϕ and its derivatives give constraints on these parameters.
- (*) Solve these corretroints with boundary condition $\phi=0$ out-side the pattern, and logarithmic divergence near the centre.

The constraints are hard to solve in a general pattern. However, it is possible to explicitly solve thme constraints in certain examples. The squee soid ASM has a large nange of dissert kinds of patches and nather complex to begin with. We (ideas of Deepak Dhan) constructed relatively simpler models where the above constraints can be solved explicitly.

Example 18 Pattern on a directed triangular lattice. [Sadhu, Dhar, PRE, 85,021107 (2012)]

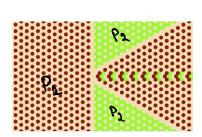


Threshold height 2c = 3

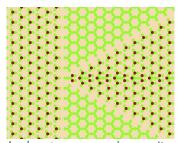


Properties:

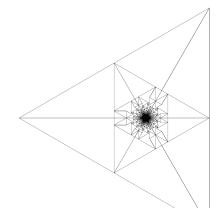
- (1) These are Sost-growing patterns $N_H \sim N$ for large N. Added grains get distributed along 1d curves.
- (2) There are only two kinds of patches, both of same areal density equal to the background density.
- (3) Potch boundaries are straight lines of slopes $0, \frac{\pi}{6}, \frac{2\pi}{6}, \cdots, \frac{5\pi}{6}$.



Both patches P1 and P2 have some unit cell density



Periodicity in a similar pattern



Plot of difference of whit cell density with nespect to background density $4P = P - P_0$

Added grains accumulate along the patch boundaries denoted by black straight lines. Along these lines average change in hight $-\frac{1}{13}$, 1, $\frac{2}{13}$

(a) Equation for the nescaled toppling function.

emsmo resilies we privallet

$$\begin{pmatrix} V^{\prime\prime} \\ \partial^2 \mathcal{F} + \partial^2 \mathcal{F} \end{pmatrix} \phi(\mathcal{F}^{\prime\prime}) = \begin{pmatrix} \delta^{\prime\prime} \mathcal{F} \\ \delta^{\prime\prime} \mathcal{F} \end{pmatrix} - \begin{pmatrix} V^{\prime\prime} \\ V^{\prime\prime} \\ \mathcal{F} \end{pmatrix} \delta(\mathcal{F}) \delta(\mathcal{F})$$

$$(\bar{\kappa})\delta - (\bar{\kappa})\tau = (\bar{\kappa})\varphi^{\mathcal{L}}$$

 $\overline{n} \equiv (3,2)$ o(x) = line change density.

(b) Inside each patch ϕ is linear

$$\phi_p(\bar{x}) = d_p g + e_p g + g_p$$

so only three parameters to determine.

(c) Conditions at the boundary of these patches.

$$\phi_P = \phi_{P'}$$
 and

$$\phi_P = \phi_{P'}$$
 and $\psi_P = \phi_{P'} = \sigma$

T unit rector perpendicular to patch boundary.

<u>Remarks</u> For this pattern, it turns out that $T_N(\bar{x})$ is itself linear inside patches.

$$T_N(\bar{R}) = A_P + \bar{K}_{P^{\circ}\bar{R}} + F_{Periodic}(\bar{R})$$

 $T_N(\bar{R}) = A_P + \bar{K}_{P} \cdot \bar{R} + \mathcal{F}_{Periodic}(\bar{R})$ Then, if \hat{c}_1 , \hat{c}_2 are basis vectors of unit cell of the periodicity inside the patch,

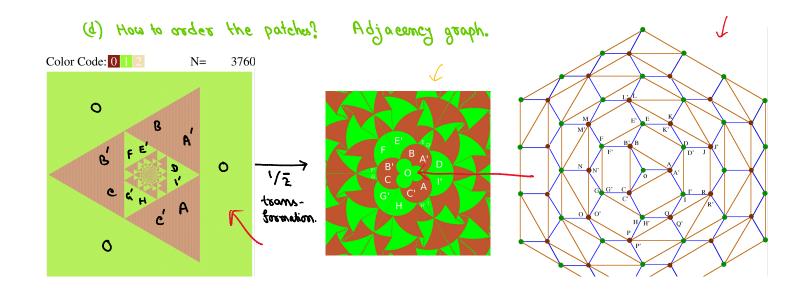
$$T_{N}(\bar{k}+\hat{e}_{i(2)})-T_{N}(\bar{k})=\bar{k}_{p}\cdot\hat{e}_{i(2)}$$

As The integer valued, Kp.ê, (a) = integer. If g, g, one reciprocal vectors

then

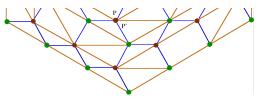
$$\overline{K}_{p} = m \, \hat{g}_{1} + n \, \hat{g}_{2}$$
 with (m,n) integers.

For our example, ê, ê, goom triangular lattice => \$1, \$2 form hexagonal lattice.





Observe how postenes (A, A') are treated as same node. Sums for other pairs.



Adjacency grouph

On the adjacency graph.

(1) Each node position can be denoted by

$$D = m + n \omega \qquad \text{with} \qquad \omega = \text{cube nod of waity.}$$

$$= e^{i 2\pi/3}$$

$$(-1,-1) \qquad \text{omd} \qquad (1+\omega+\omega^2=0)$$

Therefore each patch is associated with a pair of integers (m,n).

(2) If we consider the motehing conditions $\widehat{n} \cdot \nabla (\varphi_p - \varphi_p) = \nabla \qquad \text{with} \qquad \nabla = -\frac{1}{\sqrt{3}}, \ \frac{2}{\sqrt{3}}$ along the patch boundaries we see that

$$\phi_{p} = -\frac{1}{2\sqrt{3}} \left[\mathcal{D}_{p} \overline{\lambda} + \overline{\mathcal{D}}_{p} \lambda \right] + \mathcal{G}_{p} \quad \text{with} \quad P \equiv (m, n).$$

$$\lambda = 2 + i \mathcal{D}$$

This gives the linear order terms.

(3) How do we get f_p ? Ux the second matching condition $\varphi_p = \varphi_{p'}$ along patch boundaries.

Across a potch boundary $x = ne^{i\theta} + u$ it gives

$$f_{p'} - f_{p} = Re \left[\bar{u} \left(p_{p'} - p_{p} \right) \right] \cdot \frac{1}{13}$$

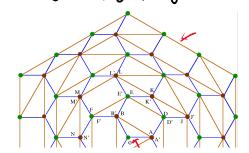
we still need additional constraint. This comes from concurrency condition.

For example, patch boundaries OA, DA, I'A' meet at same point, ic,

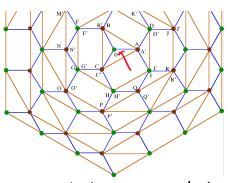
Some u. Then the above condition for

Extending this condition on all nodes on the adjacency graph gives that

df = 0 on the hexagonal graph sormed by blue edges. [continuity condition along evange edges



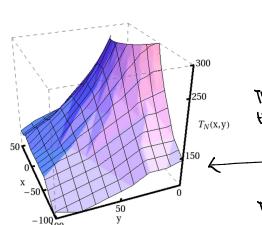
[continuity condition along orange edges are automatically satisfied]



(9) Then f_p is discrete hormonic on hexaganal graph with f = 0 for (0,0) node which corresponds to outside of the pattern.

Solution
$$g_{mn} = \frac{e}{4\pi^2} \int_{-\pi}^{\pi} dk_1 dk_2 \frac{1 - \cos\left(\frac{k_1(2m-n)}{3} + k_2n\right)}{1 - \frac{\cos 2k_2 + 2\cos k_1 \cos k_2}{3}}$$

(5) How do we get C?



be mi
$$|\pi| \log \sqrt{\frac{\kappa}{n}} - \infty (\bar{\pi}) \varphi \Leftarrow$$

$$|\pi| \log \sqrt{\frac{\kappa}{n}} - \infty (\bar{\pi}) \varphi \Leftrightarrow$$

The ϕ -Sunction is a Piece-wise linear approximation to this logarithmic Sunction.

The piece-wise linear toppling sunction (only a section is shown).

This gives (See PRE 85, 021107 (2012)) $\Rightarrow \frac{3}{100} \simeq \frac{3}{100} \log |m+n\omega| \quad \text{for large } m, n.$

[More precisely it comes from a reasoning that there are complex coordinates no inside each patch (m,n) with 1m1+1n1 large, where

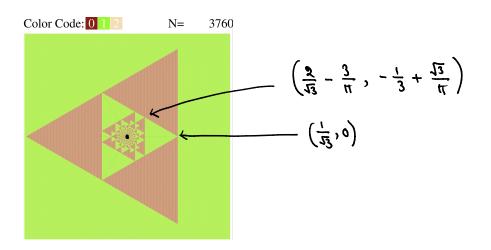
$$\frac{\partial}{\partial n} \left[\phi(n) + \psi(n) \right] = 0 \quad \text{and} \quad \phi(n_0) = \psi(n_0) \quad \text{where } \psi(n) = -\frac{1}{2n} \log |n|$$

T Keep this relation in mind as it will appear again

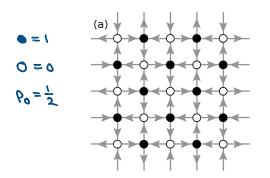
This gives
$$e = \frac{\lambda}{\sqrt{3}}$$
.

What do we get?

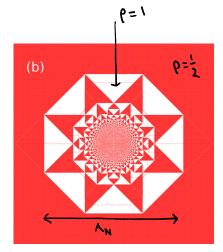
Knowing D and I determines & completely as piece-wise linear twactions. We can construct the patch boundaries from this solution. For example,



Example 2 %



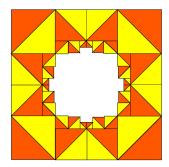
F-lattice
Trushold height 2c=2



There are two types of potches

 $0 = \frac{3}{1} \quad \text{and} \quad 0 = 1$

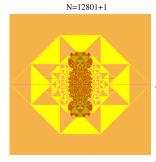
There is a correspondance with "squaring the square" a la brooks-Smith-Stone-Tutte (ask Deepak for details)



Pattern made of square tilings.

Crowth of the boundary

NN ~ IN + O(N/4) for large N.



Shaded clank
sugion shows
begion shows
to one relow a
then event.
Only when one
such avalonch
such bound any
the pattern

. 25% Midwood

Rescaled toppling sumetion

$$T_{N}(x,y) \simeq N_{N} \varphi(x,y)$$
 for large N.

ewollof II

$$\Delta \phi = 6 - 6^{\circ} - y \, \delta(\underline{y})$$

gives coess 1.

The \$ function is piece-wise quadratic.

$$\phi = \frac{1}{8} (1+m) 3^2 + \frac{1}{4} n 3 2 + \frac{1}{8} (1-m) 2^2 + d 2 + e 2 + f$$

in patch P= 1.

$$\phi = \frac{8}{7}m_{2}^{2} + \frac{4}{7}m_{2}^{2} - \frac{9}{7}m_{2}^{2} + 62 + 62 + \frac{9}{7}$$

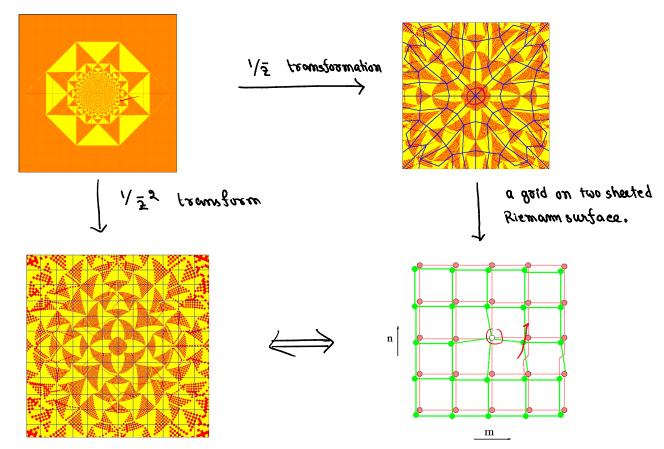
in patch $\rho = \frac{1}{2}$.

Matching conditions along patch boundaries.

Matching conditions along patch boundaries.

$$\hat{\nabla} \cdot \vec{\Delta} \left(\phi^b - \phi^b \right) = 0 \qquad \text{and} \quad \phi^b = \phi^b$$

To solve the constraints, amonge the patches



Following the matching condition

$$\mathcal{L} \cdot \Delta \left(\phi^b - \phi^{b_i} \right) = 0$$

we see that (m,n) are integer indices of the square gold on a doubly sheeted Rieman surface.

How do we determine just of the coessicients die, and 9?

We the second motching condition

$$\phi^b = \phi^b$$

It gives $D_p = d_p + ie_p$ as discrete holomorphic sunction on the adjacency graph, ie it follows discrete Cauchy-Riemann condition except at origin.

As consequence, Do is discrete harmonic.

40,=0 on two sheeted Riemann Surface with branch point at origin.

Boundary conditions

Boundary conditions

(become no toppling outside pattern)

$$D_p \equiv D_{m,n} = \pm \frac{\lambda}{\sqrt{2\pi}} \sqrt{m+in}$$
 for large m,n . The court of logarithmic divergence of ϕ are

divergence of p near

centre of the pattern)

(± one for two sheets.)

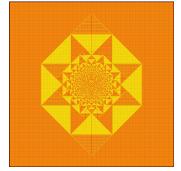
Then D is discrete analogue of IZ.

The coessicient of is expressed interms of D, following the modeling condition.

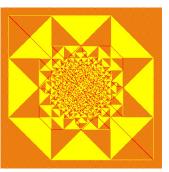
A sew simple consequences:

- (1) patch boundaries can be determined.
- (2) We can show that the pattern has eight-fold symmetry.
- (3) Number of patches n(A) with one of scales as $\gamma(A) \sim 1/45/3$

Remark: There are more than one backgrounds which gives same asymptotic pattern. Also disserent lattices can give same pattern.



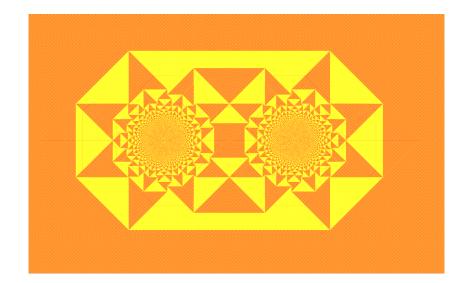
on F-lattice with discount back ground



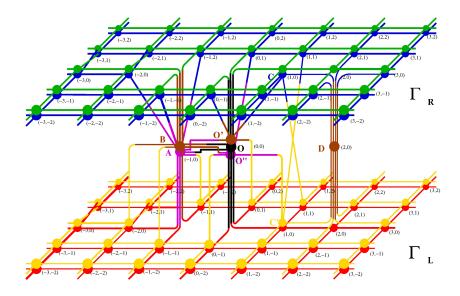
on Manhadom lattice

nomhatton lattice.

Example 3 % Multiple addition sites.

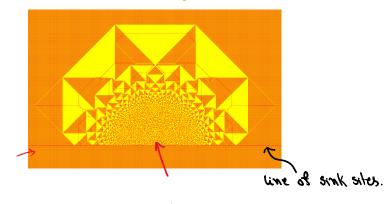


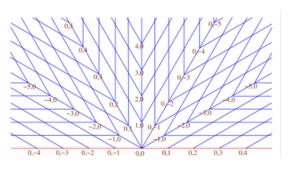
grains are added at two points at separation $\Delta x = \alpha \cdot ln$ on the F-lattice.



Adjacency graph.

Example 4: Absorbing lines





Adjacency graph

a) vn ~ n/3

Other geometries of sink sites
(3) Inside a wedge of sink lines of angle 0

 $V^{\mu} \sim N_{\chi}$ with $\alpha = \frac{7 + \frac{6}{u}}{1}$

(3) If the sink site is adjacent to the addition site

M ~ Jugn.

Example 5: Intermediate growth note is possible even without a sink site.

